Product data sheet

1. General description

N-channel enhancement mode Field-Effect Transistor (FET) in a leadless ultra small DFN1006-3 (SOT883) Surface-Mounted Device (SMD) plastic package using Trench MOSFET technology.

2. Features and benefits

- Very low threshold voltage
- Very fast switching
- · Trench MOSFET technology
- ElectroStatic Discharge (ESD) protection typically > 2 kV
- Leadless ultra small SMD plastic package: 1.0 x 0.6 x 0.48 mm

3. Applications

- Relay driver
- · High-speed line driver
- · Low-side load switch
- · Switching circuits

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit	
V _{DS}	drain-source voltage	T _j = 25 °C		-	-	12	V	
V_{GS}	gate-source voltage			-6	-	6	V	
I _D	drain current	V _{GS} = 4.5 V; T _{amb} = 25 °C	[1]	-	-	1.5	А	
Static charact	Static characteristics							
R _{DSon}	drain-source on-state resistance	V _{GS} = 4.5 V; I _D = 1.2 A; T _j = 25 °C		-	170	200	mΩ	
		$V_{GS} = 1.8 \text{ V}; I_D = 0.1 \text{ A}; T_j = 25 ^{\circ}\text{C}$		-	250	400	mΩ	

^[1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 1 cm².



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5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	G	gate		D
2	S	source		
3	D	drain	Transparent top view DFN1006-3 (SOT883)	G S 017aaa255

6. Ordering information

Table 3. Ordering information

Type number	Package	ackage							
	Name	Description	Version						
PMZ170VNE		plastic, leadless ultra small package; 3 terminals; 0.35 mm pitch; 1 mm x 0.6 mm x 0.48 mm body	SOT883						

7. Marking

Table 4. Marking codes

Type number	Marking code
PMZ170VNE	N9

12 V, N-channel Trench MOSFET

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V_{DS}	drain-source voltage	T _j = 25 °C		-	12	V
V_{GS}	gate-source voltage			-6	6	V
I _D	drain current	V _{GS} = 4.5 V; T _{amb} = 25 °C	[1]	-	1.5	Α
I _{DM}	peak drain current	T_{amb} = 25 °C; single pulse; $t_p \le 10 \mu s$		-	12.8	Α
P _{tot}	total power dissipation	T _{amb} = 25 °C	[2]	-	350	mW
			[1]	-	690	mW
		T _{sp} = 25 °C		-	3	W
Tj	junction temperature			-55	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C
Source-drain	diode		•			
Is	source current	T _{amb} = 25 °C	[1]	-	0.7	А

- [1] Device mounted on an FR4 Printed-Circuit Board (PCB), single-sided copper, tin-plated, mounting pad for drain 1 cm².
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

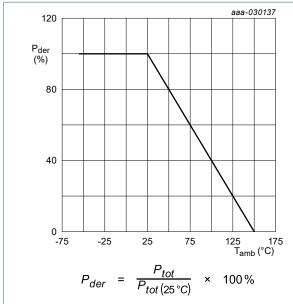


Fig. 1. Normalized total power dissipation as a function of ambient temperature

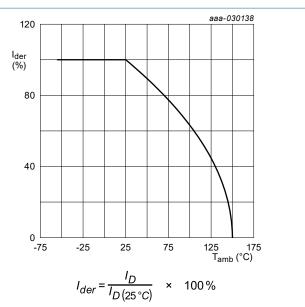


Fig. 2. Normalized continuous drain current as a function of ambient temperature

12 V, N-channel Trench MOSFET

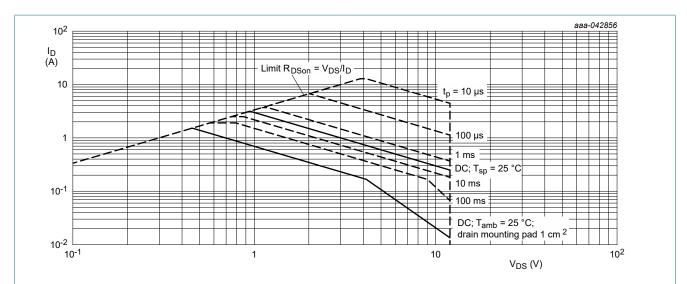


Fig. 3. Safe operating area; junction to ambient; continuous and peak drain currents as a function of drain-source voltage

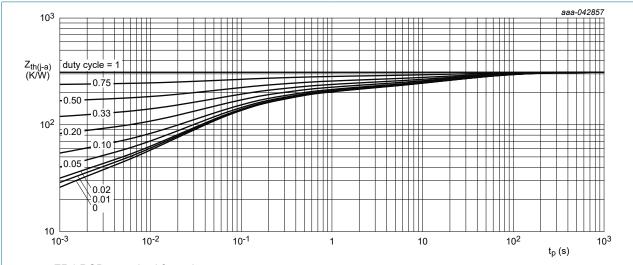
12 V, N-channel Trench MOSFET

9. Thermal characteristics

Table 6. Thermal characteristics

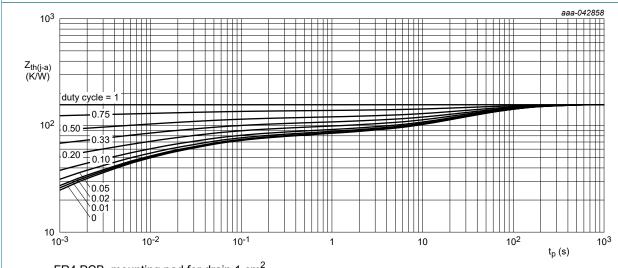
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)}	thermal resistance from	in free air	[1]	-	311	358	K/W
junction to an	junction to ambient		[2]	-	157	181	K/W
$R_{th(j-sp)}$	thermal resistance from junction to solder point			-	34	42	K/W

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for drain 1 cm².



FR4 PCB, standard footprint

Fig. 4. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values



FR4 PCB, mounting pad for drain 1 cm²

Fig. 5. Transient thermal impedance from junction to ambient as a function of pulse duration; typical values

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10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static char	acteristics					
V _{(BR)DSS}	drain-source breakdown voltage	$I_D = 250 \mu A; V_{GS} = 0 V; T_j = 25 °C$	12	-	-	V
V_{GSth}	gate-source threshold voltage	$I_D = 250 \mu A; V_{DS} = V_{GS}; T_j = 25 \text{ °C}$	0.37	0.57	0.82	V
I _{DSS}	drain leakage current	V _{DS} = 12 V; V _{GS} = 0 V; T _j = 25 °C	-	-	1	μΑ
I _{GSS}	gate leakage current	V _{GS} = 6 V; V _{DS} = 0 V; T _j = 25 °C	-	-	10	μΑ
		V _{GS} = -6 V; V _{DS} = 0 V; T _j = 25 °C	-	-	-10	μΑ
		V _{GS} = 4.5 V; V _{DS} = 0 V; T _j = 25 °C	-	-	2	μΑ
		V _{GS} = -4.5 V; V _{DS} = 0 V; T _j = 25 °C	-	-	-2	μΑ
		V _{GS} = 2.5 V; V _{DS} = 0 V; T _j = 25 °C	-	-	500	nA
		V _{GS} = -2.5 V; V _{DS} = 0 V; T _j = 25 °C	-	-	-500	nA
R _{DSon}	drain-source on-state resistance	$V_{GS} = 4.5 \text{ V}; I_D = 1.2 \text{ A}; T_j = 25 ^{\circ}\text{C}$	-	170	200	mΩ
		V _{GS} = 4.5 V; I _D = 1.2 A; T _j = 150 °C	-	250	300	mΩ
		V _{GS} = 2.5 V; I _D = 1 A; T _j = 25 °C	-	220	300	mΩ
		V _{GS} = 1.8 V; I _D = 0.1 A; T _j = 25 °C	-	250	400	mΩ
		V _{GS} = 1.5 V; I _D = 0.08 A; T _j = 25 °C	-	320	670	mΩ
		V _{GS} = 1.2 V; I _D = 0.06 A; T _j = 25 °C	-	550	2000	mΩ
9 _{fs}	forward transconductance	$V_{DS} = 5 \text{ V}; I_D = 1.2 \text{ A}; T_j = 25 \text{ °C}$	-	2.7	-	S
Dynamic cl	naracteristics				<u>'</u>	
Q _{G(tot)}	total gate charge	$V_{DS} = 6 \text{ V}; I_D = 1.2 \text{ A}; V_{GS} = 4.5 \text{ V};$	-	1.1	1.7	nC
Q _{GS}	gate-source charge	T _j = 25 °C	-	0.1	-	nC
Q _{GD}	gate-drain charge	1	-	0.4	-	nC
C _{iss}	input capacitance	V _{DS} = 6 V; f = 1 MHz; V _{GS} = 0 V;	-	66.4	-	pF
C _{oss}	output capacitance	T _j = 25 °C	-	37.6	-	pF
C _{rss}	reverse transfer capacitance		-	34.5	-	pF
t _{d(on)}	turn-on delay time	V _{DS} = 6 V; I _D = 1.2 A; V _{GS} = 4.5 V;	-	1	-	ns
t _r	rise time	$R_{G(ext)} = 6 \Omega; T_j = 25 ^{\circ}C$	-	4	-	ns
t _{d(off)}	turn-off delay time	1	-	8	-	ns
t _f	fall time	1	-	10	-	ns
Source-dra	in diode		'	-	1	
V _{SD}	source-drain voltage	I _S = 0.7 A; V _{GS} = 0 V; T _i = 25 °C	-	0.7	1.2	V

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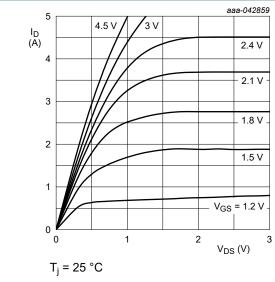


Fig. 6. Output characteristics: drain current as a function of drain-source voltage; typical values

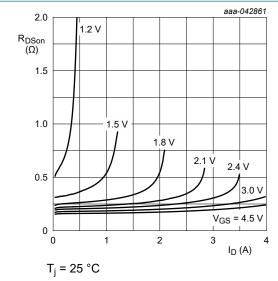


Fig. 8. Drain-source on-state resistance as a function of drain current; typical values

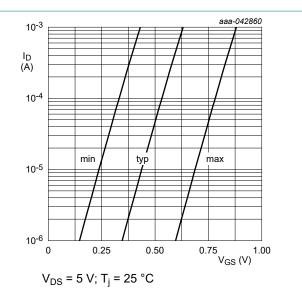


Fig. 7. Sub-threshold drain current as a function of gate-source voltage

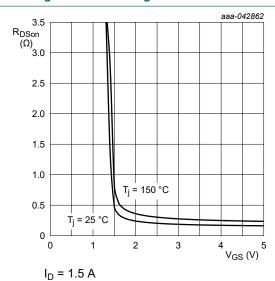


Fig. 9. Drain-source on-state resistance as a function of gate-source voltage; typical values

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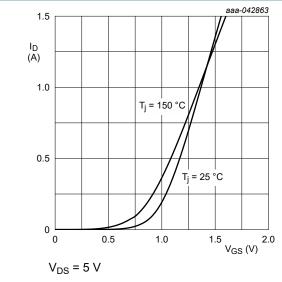


Fig. 10. Transfer characteristics: drain current as a function of gate-source voltage; typical values

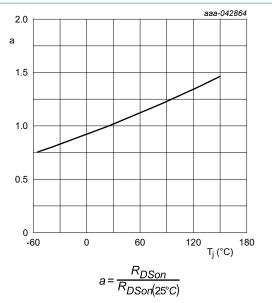


Fig. 11. Normalized drain-source on-state resistance as a function of junction temperature; typical values

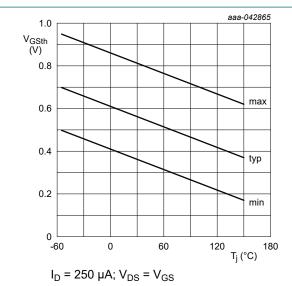


Fig. 12. Gate-source threshold voltage as a function of junction temperature

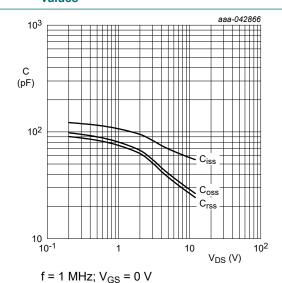


Fig. 13. Input, output and reverse transfer capacitances as a function of drain-source voltage; typical values

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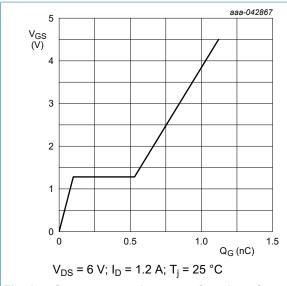


Fig. 14. Gate-source voltage as a function of gate charge; typical values

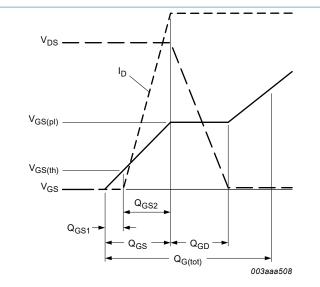


Fig. 15. Gate charge waveform definitions

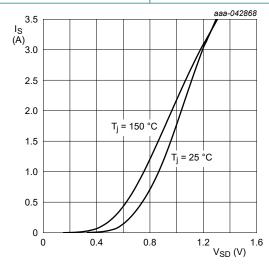
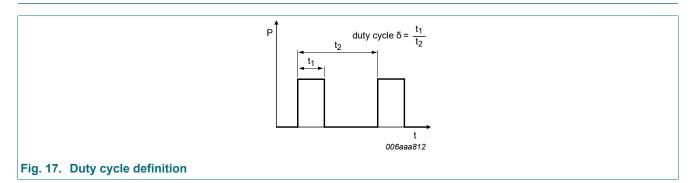


Fig. 16. Source current as a function of source-drain voltage; typical values

11. Test information

 $V_{GS} = 0 V$



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12. Package outline

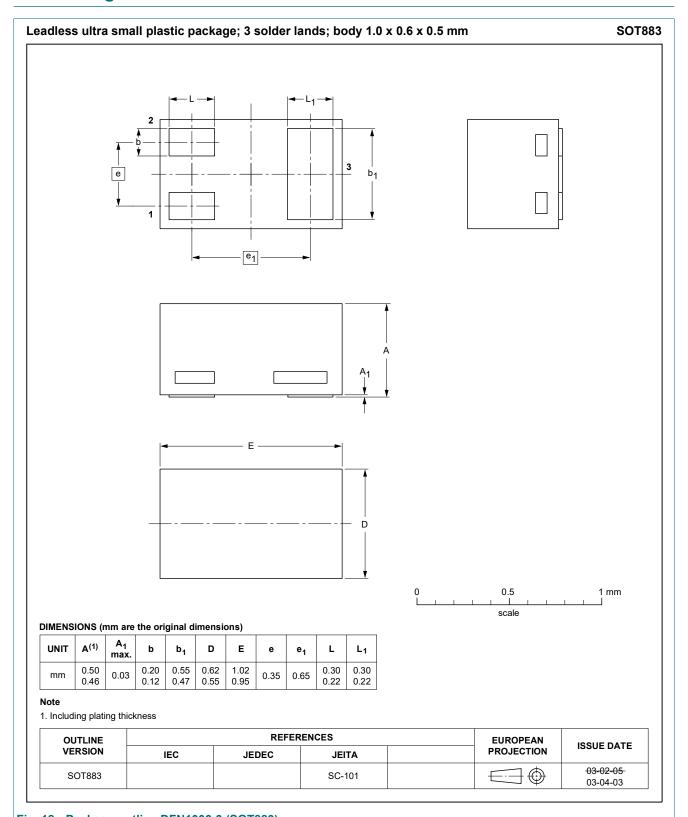
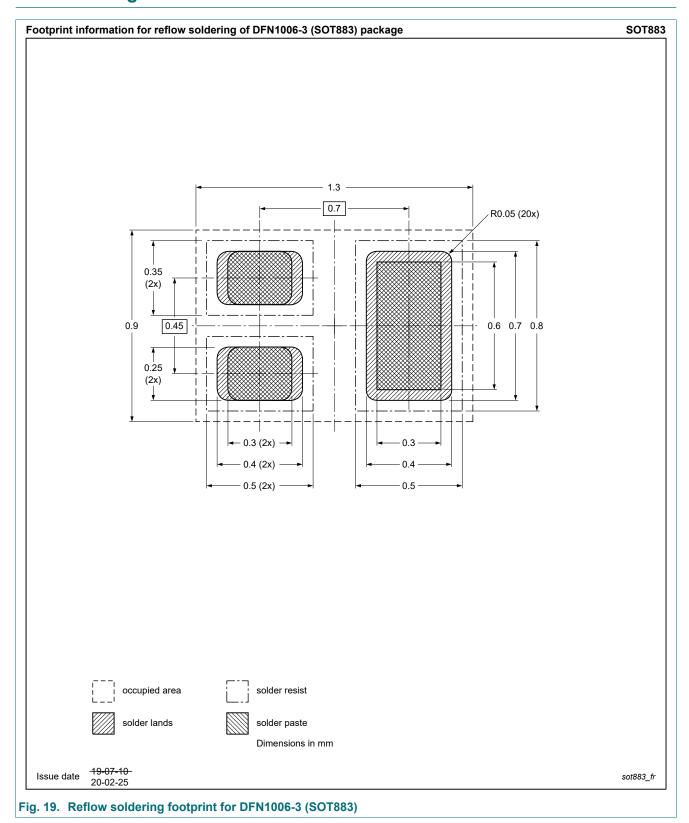


Fig. 18. Package outline DFN1006-3 (SOT883)

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13. Soldering



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14. Revision history

Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PMZ170VNE v.1	20250616	Product data sheet	-	-

12 V, N-channel Trench MOSFET

15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions".
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